Quad 2-Channel Analog Multiplexer/Demultiplexer

The MC14551B is a digitally–controlled analog switch. This device implements a 4PDT solid state switch with low ON impedance and very low OFF Leakage current. Control of analog signals up to the complete supply voltage range can be achieved.

Features

- Triple Diode Protection on All Control Inputs
- Supply Voltage Range = 3.0 Vdc to 18 Vdc
- Analog Voltage Range (V_{DD} − V_{EE}) = 3.0 to 18 V Note: V_{EE} must be ≤ V_{SS}
- Linearized Transfer Characteristics
- Low Noise $12 \text{ nV}\sqrt{\text{Cycle}}$, $f \ge 1.0 \text{ kHz}$ typical
- For Low R_{ON}, Use The HC4051, HC4052, or HC4053 High–Speed CMOS Devices
- Switch Function is Break Before Make
- NLV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC–Q100 Qualified and PPAP Capable
- This Device is Pb-Free and is RoHS Compliant

MAXIMUM RATINGS

Parameter	Symbol	Value	Unit
DC Supply Voltage Range (Referenced to V _{EE} , V _{SS} \ge V _{EE})	V _{DD}	- 0.5 to + 18.0	V
Input or Output Voltage (DC or Transient) (Referenced to V_{SS} for Control Input and V_{EE} for Switch I/O)	V _{in} , V _{out}	– 0.5 to V _{DD} + 0.5	V
Input Current (DC or Transient), per Control Pin	l _{in}	±10	mA
Switch Through Current	I _{sw}	±25	mA
Power Dissipation, per Package (Note 1)	PD	500	mW
Ambient Temperature Range	T _A	– 55 to + 125	°C
Storage Temperature Range	T _{stg}	– 65 to + 150	°C
Lead Temperature (8–Second Soldering)	ΤL	260	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. Temperature Derating: "D/DW" Package: -7.0 mW/°C From 65°C To 125°C This device contains protection dispute to guard expected damage due to high

This device contains protection circuitry to guard against damage due to high static voltages or electric fields. However, precautions must be taken to avoid applications of any voltage higher than maximum rated voltages to this high–impedance circuit. For proper operation, V_{in} and V_{out} should be constrained to the range $V_{SS} \leq (V_{in} \text{ or } V_{out}) \leq V_{DD}$ for control inputs and $V_{EE} \leq (V_{in} \text{ or } V_{out}) \leq V_{DD}$ for Switch I/O.

Unused inputs must always be tied to an appropriate logic voltage level (e.g., either V_{SS} , V_{EE} or V_{DD}). Unused outputs must be left open.



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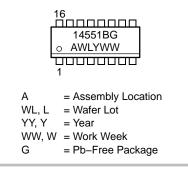
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PIN ASSIGNMENT

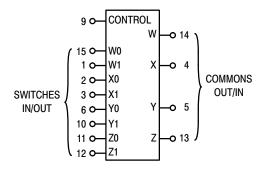
W1 [1●	16] V _{DD}
X0 [2	15] WO
X1 [3	14] W
ХC	4	13]z
ΥC	5	12] Z1
Y0 [6	11] Z0
V _{EE} [7	10] Y1
v _{ss} [8	9] CONTROI
			,

MARKING DIAGRAM



ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 2 of this data sheet.



V _{DD} = Pin 16	Control	ON
$V_{SS} = Pin 8$	0	W0 X0 Y0 Z0
V _{EE} = Pin 7	1	W1 X1 Y1 Z1

NOTE: Control Input referenced to V_{SS}, Analog Inputs and Outputs reference to V_{EE}. V_{EE} must be \leq V_{SS}.

ORDERING INFORMATION

Device	Package	Shipping [†]
MC14551BDG	SOIC-16 (Pb-Free)	48 Units / Rail
MC14551BDR2G	SOIC-16 (Pb-Free)	2500 / Tape & Reel
NLV14551BDR2G*	SOIC-16 (Pb-Free)	2500 / Tape & Reel

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

*NLV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC–Q100 Qualified and PPAP Capable.

ELECTRICAL CHARACTERISTICS

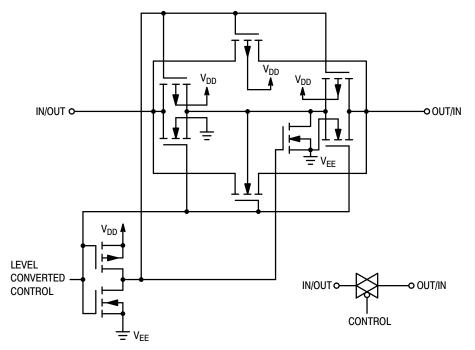
				– 55°C		25°C			125°C		
Characteristic	V _{DD}	Test Conditions	Symbol	Min	Max	Min	Typ (Note 2)	Max	Min	Max	Unit
SUPPLY REQUIREMENTS (Voltage	es Referenced to V _{EE})			•				•	•	
Power Supply Voltage Range	-	$V_{DD} - 3.0 \ge V_{SS} \ge V_{EE}$	V _{DD}	3.0	18	3.0	-	18	3.0	18	V
Quiescent Current Per Package	5.0 10 15	$\begin{array}{l} \mbox{Control Inputs: } V_{in\ =} \\ V_{SS} \mbox{ or } V_{DD}, \\ \mbox{Switch I/O: } V_{EE} \leq V_{I/O} \\ \leq V_{DD}, \mbox{ and } \Delta V_{switch} \leq \\ 500 \mbox{ mV (Note 3)} \end{array}$	I _{DD}		5.0 10 20	_ _ _	0.005 0.010 0.015	5.0 10 20		150 300 600	μΑ
Total Supply Current (Dynamic Plus Quiescent, Per Package)	5.0 10 15	$\label{eq:T_A} \begin{array}{l} T_A = 25^\circ C \text{ only (The} \\ \text{channel component,} \\ (V_{in} - V_{out})/R_{on}, \text{ is} \\ \text{not included.)} \end{array}$	I _{D(AV)}			Typical	(0.07 μΑ/ (0.20 μΑ/ (0.36 μΑ/	′kHz) f +	I _{DD}		μΑ
CONTROL INPUT (Voltages	Refere	nced to V _{SS})									
Low-Level Input Voltage	5.0 10 15	R _{on} = per spec, I _{off} = per spec	V _{IL}	_ _ _	1.5 3.0 4.0	_ _ _	2.25 4.50 6.75	1.5 3.0 4.0	_ _ _	1.5 3.0 4.0	V
High-Level Input Voltage	5.0 10 15	R _{on} = per spec, I _{off} = per spec	V _{IH}	3.5 7.0 11	- - -	3.5 7.0 11	2.75 5.50 8.25	- - -	3.5 7.0 11	- - -	V
Input Leakage Current	15	$V_{in} = 0 \text{ or } V_{DD}$	l _{in}	-	±0.1	-	±0.00001	±0.1	-	±1.0	μΑ
Input Capacitance	-		C _{in}	-	-	-	5.0	7.5	-	-	pF
SWITCHES IN/OUT AND CO	MMON	IS OUT/IN — W, X, Y, Z (\	/oltages Re	ference	ed to V _E	E)					
Recommended Peak-to- Peak Voltage Into or Out of the Switch	-	Channel On or Off	V _{I/O}	0	V _{DD}	0	-	V _{DD}	0	V _{DD}	V _{p-p}
Recommended Static or Dynamic Voltage Across the Switch (Note 3) (Figure 3)	_	Channel On	ΔV_{switch}	0	600	0	-	600	0	300	mV
Output Offset Voltage	-	V _{in} = 0 V, No Load	V _{OO}	-	-	-	10	-	-	-	μV
ON Resistance	5.0 10 15	$\begin{array}{l} \Delta V_{switch} \leq 500 \text{ mV} \\ (\text{Note 3}), \\ V_{in} = V_{IL} \text{ or } V_{IH} \\ (\text{Control}), \text{ and } V_{in} = 0 \text{ to} \\ V_{DD} \text{ (Switch)} \end{array}$	R _{on}		800 400 220		250 120 80	1050 500 280		1200 520 300	Ω
Δ ON Resistance Between Any Two Channels in the Same Package	5.0 10 15		ΔR_{on}		70 50 45	_ _ _	25 10 10	70 50 45	_ _ _	135 95 65	Ω
Off–Channel Leakage Current (Figure 8)	15	V _{in} = V _{IL} or V _{IH} I _{off} (Control) Channel to Channel or Any One Channel		-	±100	_	±0.05	±100	_	±1000	nA
Capacitance, Switch I/O	-	Switch Off	C _{I/O}	I	-	-	10	-	-	-	pF
Capacitance, Common O/I	-		C _{O/I}	-	-	-	17	-	-	-	pF
Capacitance, Feedthrough (Channel Off)	_ _	Pins Not Adjacent Pins Adjacent	C _{I/O}	-		-	0.15 0.47		-	_ _	pF

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions. 2. Data labeled "Typ" is not to be used for design purposes, but is intended as an indication of the IC's potential performance.

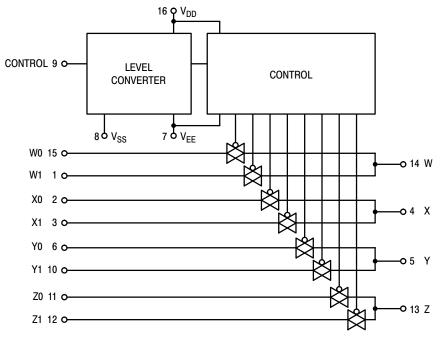
For voltage drops across the switch (ΔV_{switch}) > 600 mV (> 300 mV at high temperature), excessive V_{DD} current may be drawn; i.e. the current out of the switch may contain both V_{DD} and switch input components. The reliability of the device will be unaffected unless the Maximum Ratings are exceeded. (See first page of this data sheet.)

Characteristic	Symbol	V _{DD} – V _{EE} Vdc	Min	Typ (Note 4)	Max	Unit
Propagation Delay Times Switch Input to Switch Output ($R_L = 10 \text{ k}\Omega$) t_{PLH} , $t_{PHL} = (0.17 \text{ ns/pF}) C_L + 26.5 \text{ ns}$ t_{PLH} , $t_{PHL} = (0.08 \text{ ns/pF}) C_L + 11 \text{ ns}$ t_{PLH} , $t_{PHL} = (0.06 \text{ ns/pF}) C_L + 9.0 \text{ ns}$	t _{PLH} , t _{PHL}	5.0 10 15	_	35 15 12	90 40 30	ns
Control Input to Output ($R_L = 10 \text{ k}\Omega$) V _{EE} = V _{SS} (Figure 4)	t _{PLH} , t _{PHL}	5.0 10 15	_	350 140 100	875 350 250	ns
Second Harmonic Distortion $R_L = 10 \text{ k}\Omega, \text{ f} = 1 \text{ kHz}, \text{ V}_{in} = 5 \text{ V}_{p-p}$	_	10	-	0.07	-	%
Bandwidth (Figure 5) $R_L = 1 \text{ k}\Omega$, $V_{in} = 1/2 (V_{DD} - V_{EE})_{p-p}$, 20 Log (V_{out}/V_{in}) = - 3 dB, $C_L = 50 \text{ pF}$	BW	10	_	17	-	MHz
Off Channel Feedthrough Attenuation, Figure 5 R _L = 1 kΩ, V _{in} = 1/2 (V _{DD} - V _{EE}) _{p-p} , f _{in} = 55 MHz	-	10	_	- 50	-	dB
Channel Separation (Figure 6) R _L = 1 kΩ, V _{in} = 1/2 (V _{DD} - V _{EE}) _{p-p} , f _{in} = 3 MHz	-	10	-	- 50	-	dB
Crosstalk, Control Input to Common O/I, Figure 7 R1 = 1 k Ω , R _L = 10 k Ω , Control t _r = t _f = 20 ns	-	10	-	75	-	mV

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.4. Data labelled "Typ" is not to be used for design purposes but is intended as an indication of the IC's potential performance.









TEST CIRCUITS

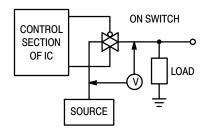


Figure 3. ΔV Across Switch

Control input used to turn ON or OFF the switch under test.

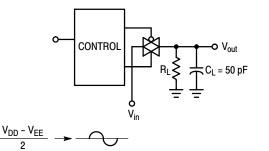


Figure 5. Bandwidth and Off–Channel Feedthrough Attenuation

R1

<u>]</u>

Figure 7. Crosstalk, Control Input

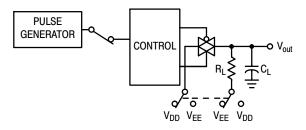
to Common O/I

Vout

C₁ = 50 pF

 \circ

CONTROL





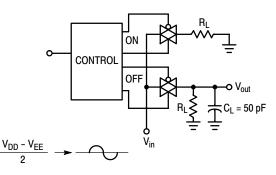


Figure 6. Channel Separation (Adjacent Channels Used for Setup)

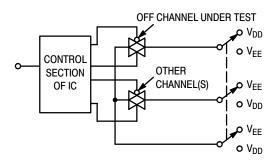
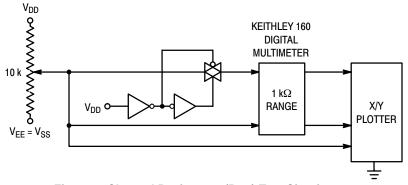
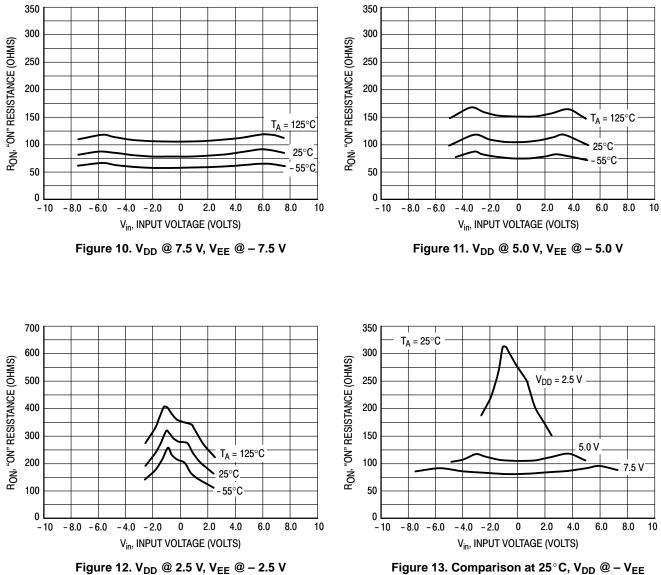


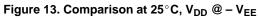
Figure 8. Off Channel Leakage











APPLICATIONS INFORMATION

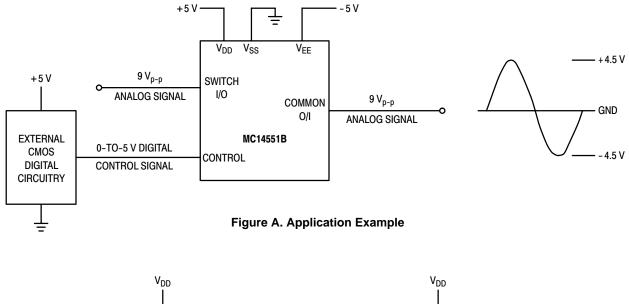
Figure A illustrates use of the on-chip level converter detailed in Figure 2. The 0-to-5.0 V Digital Control signal is used to directly control a 9 V_{p-p} analog signal.

The digital control logic levels are determined by V_{DD} and V_{SS} . The V_{DD} voltage is the logic high voltage; the V_{SS} voltage is logic low. For the example, $V_{DD} = +5.0 \text{ V} = \text{logic}$ high at the control inputs; $V_{SS} = \text{GND} = 0 \text{ V} = \text{logic}$ low.

The maximum analog signal level is determined by V_{DD} and V_{EE} . The V_{DD} voltage determines the maximum recommended peak above V_{SS} . The V_{EE} voltage determines the maximum swing below V_{SS} . For the example, $V_{DD} - V_{SS}$ = 5.0 V maximum swing above V_{SS} ; $V_{SS} - V_{EE} = 5.0$ V maximum swing below V_{SS} . The example shows a ± 4.5 V signal which allows a 1/2 V margin at each peak. If voltage transients above V_{DD} and/or below V_{EE} are anticipated on the analog channels, external diodes (D_x) are recommended as shown in Figure B. These diodes should be small signal types able to absorb the maximum anticipated current surges during clipping.

The absolute maximum potential difference between V_{DD} and V_{EE} is 18 V. Most parameters are specified up to 15 V which is the recommended maximum difference between V_{DD} and V_{EE} .

Balanced supplies are not required. However, V_{SS} must be greater than or equal to V_{EE} . For example, $V_{DD} = +10$ V, $V_{SS} = +5.0$ V, and $V_{EE} = -3.0$ V is acceptable. See the table below.



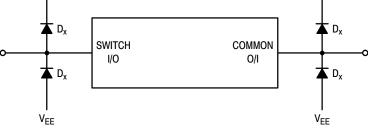


Figure B. External Schottky or Germanium Clipping Diodes

POSSIBLE SUPPLY CONNECTIONS

V _{DD} In Volts	V _{SS} In Volts	V _{EE} In Volts	Control Inputs Logic High/Logic Low In Volts	Maximum Analog Signal Range In Volts
+ 8	0	- 8	+ 8/0	+ 8 to - 8 = 16 V _{p-p}
+ 5	0	- 12	+ 5/0	+ 5 to – 12 = 17 V_{p-p}
+ 5	0	0	+ 5/0	+ 5 to 0 = 5 V _{p-p}
+ 5	0	- 5	+ 5/0	+ 5 to – 5 = 10 V _{p–p}
+ 10		- 5	+ 10/ + 5	+ 10 to $-5 = 15 V_{p-p}$

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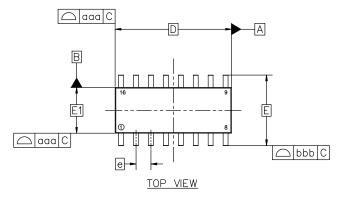
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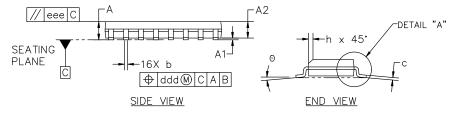
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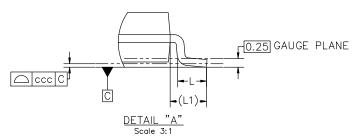
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NOTES:

- 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 2018.
- 2. DIMENSION IN MILLIMETERS. ANGLE IN DEGREES.
- 3. DIMENSIONS D AND E1 DO NOT INCLUDE MOLD PROTRUSION.
- 4. MAXIMUM MOLD PROTRUSION 0.15mm PER SIDE.
- DIMENSION b DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.127mm TOTAL IN EXCESS OF THE b DIMENSION AT MAXIMUM MATERIAL CONDITION.

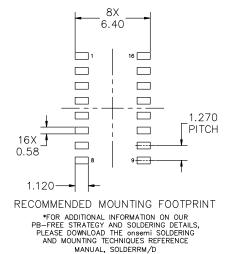






DIM	MIN NOM MAX						
A	1.35	1.55	1.75				
A1	0.00	0.05	0.10				
A2	1.35	1.50	1.65				
b	0.35	0.42	0.49				
с	0.19	0.22	0.25				
D		9.90 BSC					
E		6.00 BSC					
E1		3.90 BSC					
е	1.27 BSC						
h	0.25		0.50				
L	0.40	0.83	1.25				
L1		1.05 REF					
Θ	0.		7'				
TOLERAN	CE OF FC	RM AND	POSITION				
aaa	0.10						
bbb		0.20					
ccc	0.10						
ddd	0.25						
eee		0.10					

MILLIMETERS



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DATE 29 MAY 2024

GENERIC MARKING DIAGRAM*

16	F	A	H	A	H	A	A	A	
		XX							
		XX	XX)	XX	XX)	XX	XX	X	
	AWLYWW								
1	Ŧ	H	H	H	H	H	H	Ŧ	I

XXXXX = Specific Device Code

A = Assembly Location

- WL = Wafer Lot
- Y = Year
- WW = Work Week
- G = Pb-Free Package

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.

STYLE 1:		STYLE 2:		STYLE 3:		STYLE 4:	
PIN 1.	COLLECTOR	PIN 1.	CATHODE	PIN 1.		PIN 1.	COLLECTOR, DYE #1
2.	BASE	2.	ANODE	2.	BASE, #1	2.	
3.	EMITTER	3.	NO CONNECTION	3.	EMITTER, #1	3.	
4.	NO CONNECTION	4.	CATHODE	4.		4.	
5.	EMITTER	5.	CATHODE	5.	COLLECTOR, #2	5.	
6.	BASE	6.	NO CONNECTION	6.	BASE, #2	6.	COLLECTOR, #3
7.	COLLECTOR	7.	ANODE	7.	EMITTER, #2	7.	COLLECTOR, #4
8.	COLLECTOR	8.	CATHODE	8.	COLLECTOR, #2	8.	COLLECTOR, #4
9.	BASE	9.	CATHODE	9.	COLLECTOR, #3	9.	BASE, #4
10.	EMITTER	10.	ANODE	10.	BASE, #3	10.	EMITTER, #4
11.	NO CONNECTION	11.	NO CONNECTION	11.	EMITTER, #3	11.	BASE, #3
12.	EMITTER	12.	CATHODE	12.	COLLECTOR, #3	12.	EMITTER, #3
13.	BASE	13.	CATHODE	13.	COLLECTOR, #4	13.	BASE, #2
14.	COLLECTOR	14.	NO CONNECTION	14.	BASE, #4	14.	EMITTER, #2
15.	EMITTER	15.	ANODE	15.	EMITTER, #4	15.	BASE, #1
16.	COLLECTOR	16.	CATHODE	16.	COLLECTOR, #4	16.	EMITTER, #1
STYLE 5:		STYLE 6:		STYLE 7:			
PIN 1.	DRAIN, DYE #1	PIN 1.	CATHODE	PIN 1.	SOURCE N-CH		
2.	DRAIN, #1	2.	CATHODE	2.	COMMON DRAIN (OUTPUT)	
3.	DRAIN, #2	3.	CATHODE	3.	COMMON DRAIN (OUTPUT)	
4.	DRAIN, #2	4.	CATHODE	4.	GATE P-CH		
5.	DRAIN, #3	5.	CATHODE	5.	COMMON DRAIN (OUTPUT)	
6.	DRAIN, #3	6.	CATHODE	6.	COMMON DRAIN (OUTPUT)	
7.	DRAIN, #4	7.	CATHODE	7.	COMMON DRAIN (OUTPUT)	
8.	DRAIN, #4	8.	CATHODE	8.	SOURCE P-CH		
9.	GATE, #4	9.	ANODE	9.	SOURCE P-CH		
10.	SOURCE, #4	10.	ANODE	10.	COMMON DRAIN (OUTPUT)	
11.	GATE, #3	11.	ANODE	11.	COMMON DRAIN (OUTPUT)	
12.	SOURCE, #3	12.	ANODE	12.)	
13.	GATE, #2		ANODE	13.			
14.	SOURCE, #2		ANODE	14.			
15.	GATE, #1	15.	ANODE	15.)	
16.	SOURCE, #1	16.	ANODE	16.	SOURCE N-CH		

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